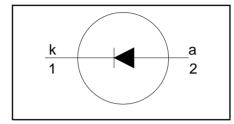
BY229 series

FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

 $V_R = 200 \text{ V/ } 400 \text{ V/ } 600 \text{ V/800 V}$ $I_{F(AV)} = 8 \text{ A}$ $I_{FSM} \le 60 \text{ A}$ $t_{rr} \le 135 \text{ ns}$

GENERAL DESCRIPTION

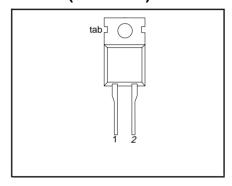
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY229 series is supplied in the conventional leaded SOD59 (TO220AC) package.

PINNING

PIN	DESCRIPTION		
1	cathode		
2	anode		
tab	cathode		

SOD59 (TO220AC)



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN. MAX.		UNIT			
V_{RSM}	Peak non-repetitive reverse voltage	BY229	-	-200 200	-400 400	-600 600	-800 800	V
$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage		- - -	200 150 150	400 300 300	600 500 500	800 600 600	V V V
I _{F(AV)}	Average forward current ¹	square wave; $\delta = 0.5$; $T_{mb} \le 122 ^{\circ}C$	-		8	3		A
		sinusoidal; a = 1.57; $T_{mb} \le 125 ^{\circ}C$	-		7	7		A
I _{F(RMS)}	RMS forward current Repetitive peak forward current		- -		1 1	1 6		A A
I _{FSM}	Non-repetitive peak forward current.	t = 10 ms t = 8.3 ms sinusoidal; T _j = 150 °C prior to surge; with	-			0 6		A A
I ² t T _{stg} T _j	I ² t for fusing Storage temperature Operating junction temperature	reapplied V _{RWM(max)} t = 10 ms	-40 -		15	8 50 50		A ² s °C °C

¹ Neglecting switching and reverse current losses.

BY229 series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	2.0	K/W
R _{th j-a}		in free air.	-	60	-	K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

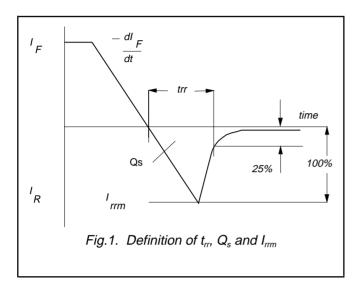
3	SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
1	V _F	Forward voltage Reverse current	$I_F = 20 \text{ A}$ $V_R = V_{RWM}$; $T_j = 125 ^{\circ}\text{C}$		1.5 0.1	1.85 0.4	V mA

DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t _{rr} Q _s dl _R /dt	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$		100 0.5 50	135 0.7 60	ns μC A/μs

BY229 series



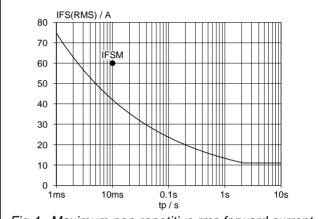


Fig.4. Maximum non-repetitive rms forward current. $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^{\circ} C$ prior to surge with reapplied V_{RWM} .

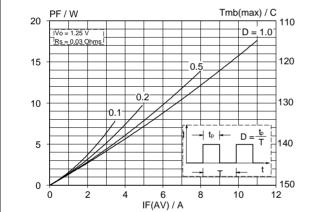


Fig.2. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; square wave current waveform; parameter D = duty $cycle = t_p/T$.

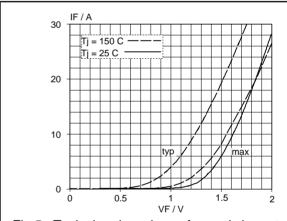


Fig.5. Typical and maximum forward characteristic; $I_F = f(V_F)$; parameter T_j

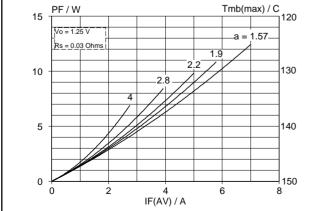
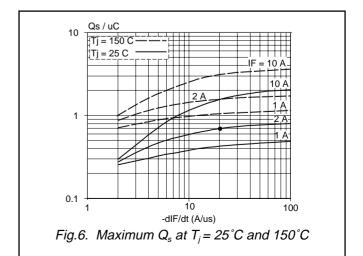
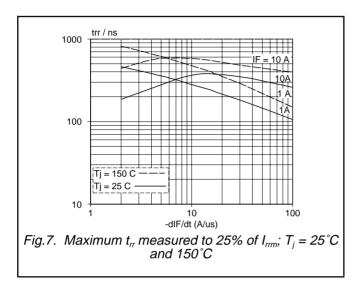
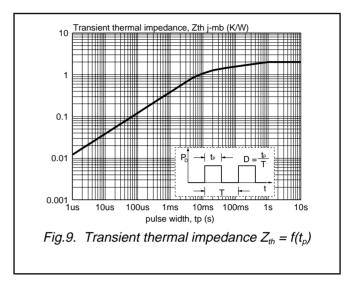


Fig.3. Maximum forward dissipation, $P_F = f(I_{F(AV)})$; sinusoidal current waveform; parameter a = form factor $= I_{F(RMS)}/I_{F(AV)}$.



BY229 series





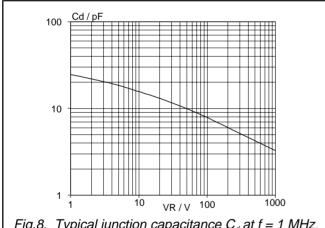
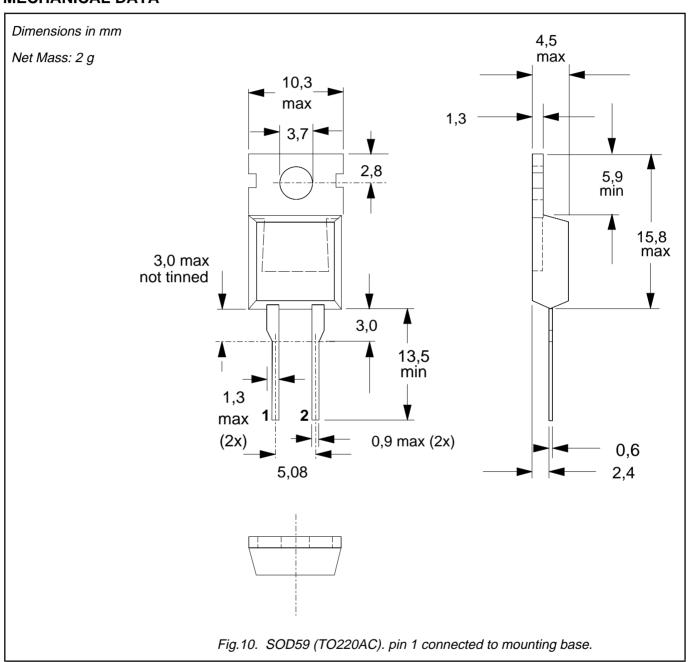


Fig.8. Typical junction capacitance C_d at f = 1 MHz, $T_j = 25^{\circ}C$

BY229 series

MECHANICAL DATA



- Refer to mounting instructions for TO220 envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes fast, soft-recovery

BY229 series

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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